

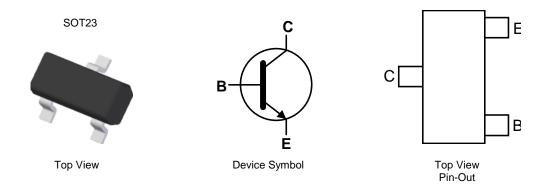
60V NPN MEDIUM POWER TRANSISTOR IN SOT23

Features

- BV_{CEO} > 60V
- BV_{CEX} > 150V
- BV_{ECO} > 6V
- I_C = 3.5A high Continuous Collector Current
- V_{CE(SAT)} < 65mA @1A
- $R_{CE(SAT)} = 43m\Omega$ @1A
- 1.25W Power Dissipation
- Complementary PNP Type: ZXTP25060BFH
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- UL Flammability Rating 94V-0
- Case Material: Molded Plastic. "Green" Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.008 grams (Approximate)



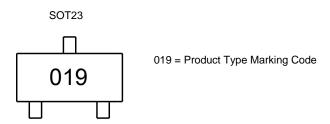
Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|----------------|------------|---------|--------------------|-----------------|-------------------|
| ZXTN25060BFHTA | AEC-Q101 | 019 | 7 | 8 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 150 | V |
| Collector-Emitter Voltage (Forward Blocking) | V _{CEX} | 150 | V |
| Collector-Emitter Voltage | V _{CEO} | 60 | V |
| Emitter-Collector Voltage (Reverse Blocking) | V _{ECO} | 6 | V |
| Emitter-Base Voltage | V _{EBO} | 7 | V |
| Continuous Collector Current | Ic | 3.5 | Α |
| Peak Pulse Current | I _{CM} | 10 | Α |
| Base Current | I _B | 200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|-------|
| Power Dissipation (Note 5) | P _D | 0.73 | W |
| Linear Derating Factor | | 5.84 | mW/°C |
| Power Dissipation (Note 6) | P _D | 1.05 | W |
| Linear Derating Factor | | 8.4 | mW/°C |
| Power Dissipation (Note 7) | P _D | 1.25 | W |
| Linear Derating Factor | | 9.6 | mW/°C |
| Power Dissipation (Note 8) | P_{D} | 1.81 | W |
| Linear Derating Factor | | 14.5 | mW/°C |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{\theta JA}$ | 171 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 6) | $R_{\theta JA}$ | 119 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 7) | R _{θJA} | 100 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 8) | $R_{	heta JA}$ | 69 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 9)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

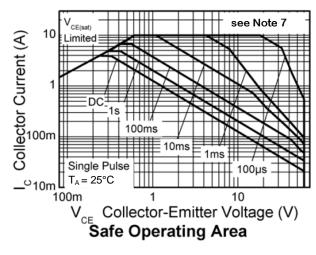
Notes:

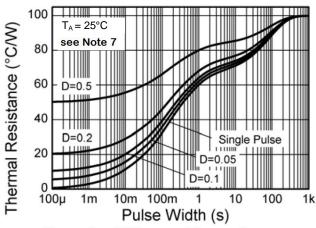
- 5. For a device surface mounted on 15mm X 15mm X 1.6mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions.
- 6. Mounted on 25mm X 25mm X 1.6mm FR-4 PCB with high coverage of single sided 2 oz copper, in still air conditions.

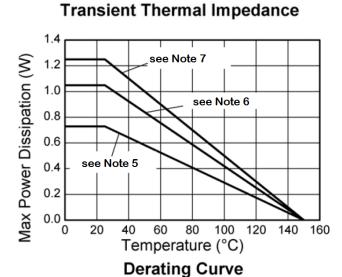
 7. Mounted on 50mm X 50mm X 1.6mm FR-4 PCB with high coverage of single sided 2 oz copper, in still air conditions.
- 8. As (7) above measured at t<5s.
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

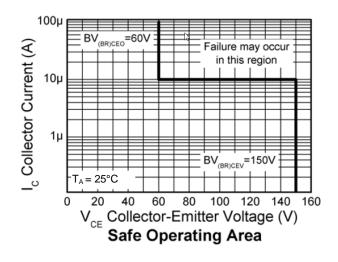


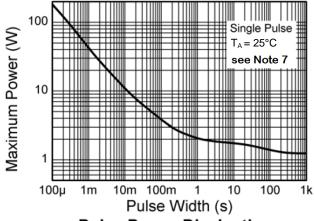
Thermal Characteristics and Derating Information











Pulse Power Dissipation



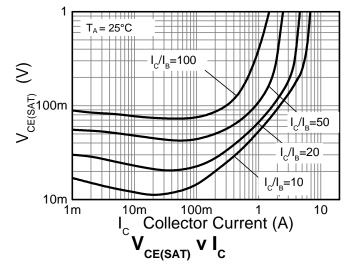
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

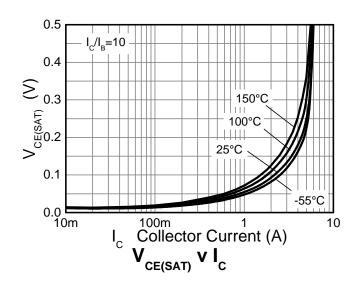
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|----------------------|-----------------|-----------------------|-----------------------|----------------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | 150 | 190 | _ | V | $I_{C} = 100 \mu A$ |
| Collector Emitter Breakdown Voltage (Forward Blocking) | BV _{CEX} | 150 | 190 | _ | V | I_C = 100μA, $R_{BE} \le 1$ k Ω or -1V < V _{BE} < 0.25V |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | 60 | 80 | _ | V | I _C = 10mA |
| Emitter-Collector Breakdown Voltage (Reverse Blocking) | BV_{ECX} | 6 | 8 | _ | V | $I_E = 100\mu A$, $R_{BE} \le 1k\Omega$ or -1V < V _{BC} < 0.25V |
| Emitter-Collector Breakdown Voltage (Base Open) | BV _{ECO} | 6 | 7 | _ | V | $I_{E} = 100 \mu A$ |
| Emitter-Base Breakdown Voltage | BV_{EBO} | 7 | 8 | _ | V | $I_{E} = 100 \mu A$ |
| Collector Cutoff Current | I _{CBO} | _ | <1 — | 50 20 | nΑ μΑ | V _{CB} = 120V V _{CB} = 120V, T _A = +100°C |
| Collector Emitter Cutoff Current | I _{CEX} | _ | _ | 100 | nA | V_{CE} = 120V, R_{BE} ≤ 1k Ω or -1V < V_{BE} < 0.25V |
| Emitter Cutoff Current | I _{EBO} | _ | <1 | 50 | nA | V _{EB} = 5.6V |
| Static Forward Current Transfer Ratio (Note 10) | h _{FE} | 100 90 25 | 200 180 40 | 300 _ _ | _ | $I_{C} = 10 \text{mA}, V_{CE} = 2 \text{V}$ $I_{C} = 1 \text{A}, V_{CE} = 2 \text{V}$ $I_{C} = 3.5 \text{A}, V_{CE} = 2 \text{V}$ |
| Collector-Emitter Saturation Voltage (Note 10) | V _{CE(SAT)} | _ | 33 73 50 150 | 40 95 65 175 | mV mV mV | $\begin{split} I_C &= 0.5 \text{A}, \ I_B = 50 \text{mA} \\ I_C &= 0.5 \text{A}, \ I_B = 10 \text{mA} \\ I_C &= 1 \text{A}, \ I_B = 100 \text{mA} \\ I_C &= 3.5 \text{A}, \ I_B = 350 \text{mA} \end{split}$ |
| Base-Emitter Turn-On Voltage (Note 10) | $V_{BE(ON)}$ | _ | 865 | 950 | mV | $I_C = 3.5$ mA, $V_{CE} = 2$ V |
| Base-Emitter Saturation Voltage (Note 10) | $V_{BE(SAT)}$ | _ | 960 | 1050 | mV | $I_C = 3.5$ mA, $I_B = 350$ mA |
| Output Capacitance (Note 10) | C_obo | | 11.5 | 20 | pF | V _{CB} = 10V, f = 1MHz |
| Transition Frequency | f _T | | 185 | _ | MHz | $V_{CE} = 5V, I_{C} = 100mA,$ f = 100MHz |
| Turn-On Time | t _{ON} | _ | 34 | _ | ns | V _{CC} =10V, I _C = 500mA |
| Turn-Off Time | t _{OFF} | _ | 566 | _ | ns | $I_{B1} = -I_{B2} = 50 \text{mA}$ |

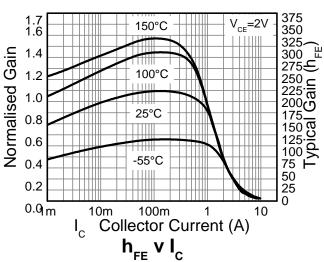
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

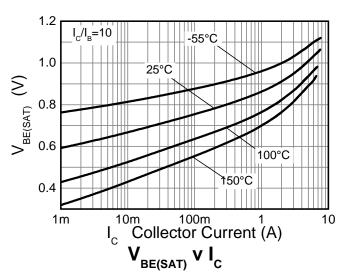


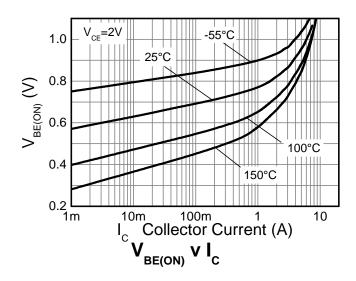
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









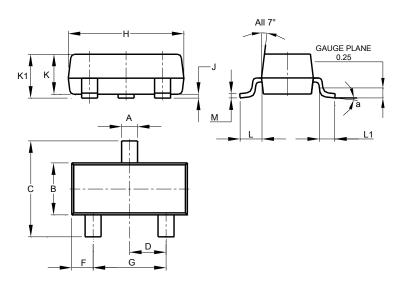




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

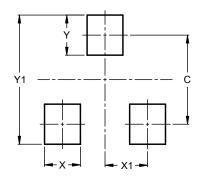


| SOT23 | | | | | | |
|----------------------|-------|-------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.37 | 0.51 | 0.40 | | | |
| В | 1.20 | 1.40 | 1.30 | | | |
| С | 2.30 | 2.50 | 2.40 | | | |
| D | 0.89 | 1.03 | 0.915 | | | |
| F | 0.45 | 0.60 | 0.535 | | | |
| G | 1.78 | 2.05 | 1.83 | | | |
| Н | 2.80 | 3.00 | 2.90 | | | |
| J | 0.013 | 0.10 | 0.05 | | | |
| K | 0.890 | 1.00 | 0.975 | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | |
| L | 0.45 | 0.61 | 0.55 | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | |
| М | 0.085 | 0.150 | 0.110 | | | |
| а | 0° | 8° | _ | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| С | 2.0 | | |
| Х | 0.8 | | |
| X1 | 1.35 | | |
| Y | 0.9 | | |
| Y1 | 2.9 | | |



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